



AiP74LVC1G32

Single 2-input Or Gate

Product Specification

Specification Revision History:

Version	Date	Description
2017-05-A1	2017-05	New
2021-09-A2	2021-09	Modify ambient temperature to $-40^{\circ}\text{C}\sim+105^{\circ}\text{C}$ and add electrical characteristics of $-40^{\circ}\text{C}\sim+105^{\circ}\text{C}$
2021-10-A3	2021-10	Modify ordering information
2021-12-A4	2021-12	Modify ordering information
2022-03-A5	2022-03	Modify ordering information note 1
2022-12-A6	2022-12	Add DFN4 packaging form



1、General Description

The AiP74LVC1G32 provides one 2-input OR function.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of these devices as translators in mixed 3.3V and 5V applications.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Features:

- Wide supply voltage range from 1.65V to 5.5V
- $\pm 24\text{mA}$ output drive ($V_{CC}=3.0\text{V}$)
- CMOS low power consumption
- Latch-up performance exceeds 250mA
- Direct interface with TTL levels
- Input accepts voltages up to 5V
- Specified from -40°C to $+105^{\circ}\text{C}$
- Packaging information: SOT23-5/SOT353/DFN4

Ordering Information:

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
AiP74LVC1G32GB235.TR	SOT23-5	ALXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.9mm×1.6mm Pin spacing: 0.95mm
AiP74LVC1G32GC353.TR	SOT353	ALXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.1mm×1.3mm Pin spacing: 0.65mm
AiP74LVC1G32XD4.TR	DFN4	ALXX	12000 PCS/reel	120000 PCS/box	Dimensions of plastic enclosure: 0.8mm×0.8mm Pin spacing: 0.5mm

Note 1: “XX” refers to variable content, meaning year and package batch serial number.

Note 2: If the physical information is inconsistent with the ordering information, please refer to the actual product.



2、Block Diagram And Pin Description

2.1、Block Diagram

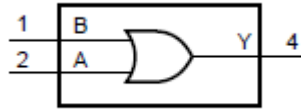


Figure 1. Logic symbol

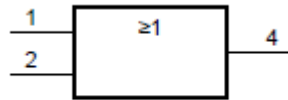


Figure 2. IEC logic symbol

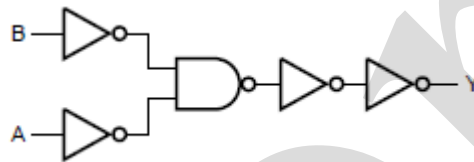
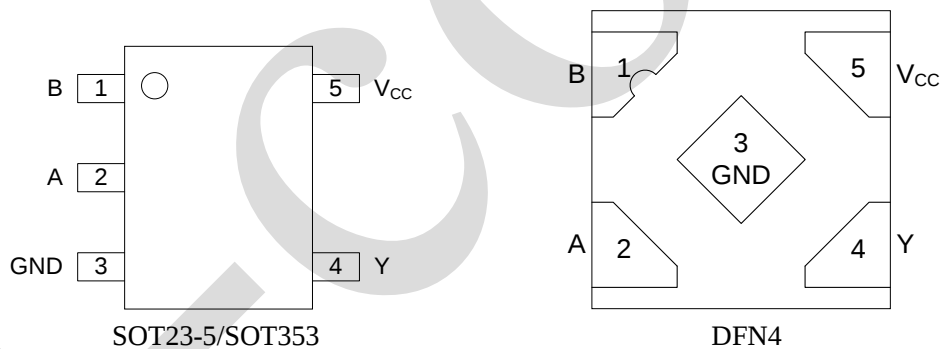


Figure 3. Logic diagram

2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	B	data input
2	A	data input
3	GND	ground (0V)
4	Y	data output
5	V _{CC}	supply voltage

**2.4、Function Table**

Input		Output
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

Note: H=HIGH voltage level; L=LOW voltage level.

3、Electrical Parameter**3.1、Absolute Maximum Ratings**

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input voltage	V_I	-	-0.5	+6.5	V
output voltage	V_O	Active mode	-0.5	$V_{CC}+0.5$	V
		Power-down mode; $V_{CC}=0V$	-0.5	+6.5	V
input clamping current	I_{IK}	$V_I < 0V$	-50	-	mA
output clamping current	I_{OK}	$V_O > V_{CC}$ or $V_O < 0V$	-	± 50	mA
output current	I_O	$V_O=0V$ to V_{CC}	-	± 50	mA
supply current	I_{CC}	-	-	100	mA
ground current	I_{GND}	-	-100	-	mA
storage temperature	T_{stg}	-	-65	+150	°C
total power dissipation	P_{tot}	-	-	250	mW
soldering temperature	T_L	10s	260		°C

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	V_{CC}	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+105	°C
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=1.65V$ to $2.7V$	-	-	20	ns/V
		$V_{CC}=2.7V$ to $5.5V$	-	-	10	ns/V



3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	$V_{CC}=1.65\text{V to }1.95\text{V}$	$0.65 \times V_{CC}$	-	-	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$	1.7	-	-	V
		$V_{CC}=2.7\text{V to }3.6\text{V}$	2.0	-	-	V
		$V_{CC}=4.5\text{V to }5.5\text{V}$	$0.7 \times V_{CC}$	-	-	V
LOW-level input voltage	V_{IL}	$V_{CC}=1.65\text{V to }1.95\text{V}$	-	-	$0.35 \times V_{CC}$	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$	-	-	0.7	V
		$V_{CC}=2.7\text{V to }3.6\text{V}$	-	-	0.8	V
		$V_{CC}=4.5\text{V to }5.5\text{V}$	-	-	$0.3 \times V_{CC}$	V
HIGH-level output voltage	V_{OH}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = -100\mu\text{A}; V_{CC}=1.65\text{V to }5.5\text{V}$	$V_{CC} - 0.1$	-	V
			$I_O = -4\text{mA}; V_{CC}=1.65\text{V}$	1.2	-	V
			$I_O = -8\text{mA}; V_{CC}=2.3\text{V}$	1.9	-	V
			$I_O = -12\text{mA}; V_{CC}=2.7\text{V}$	2.2	-	V
			$I_O = -24\text{mA}; V_{CC}=3.0\text{V}$	2.3	-	V
			$I_O = -32\text{mA}; V_{CC}=4.5\text{V}$	3.8	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = 100\mu\text{A}; V_{CC}=1.65\text{V to }5.5\text{V}$	-	-	0.10
			$I_O = 4\text{mA}; V_{CC}=1.65\text{V}$	-	-	0.45
			$I_O = 8\text{mA}; V_{CC}=2.3\text{V}$	-	-	0.30
			$I_O = 12\text{mA}; V_{CC}=2.7\text{V}$	-	-	0.40
			$I_O = 24\text{mA}; V_{CC}=3.0\text{V}$	-	-	0.55
			$I_O = 32\text{mA}; V_{CC}=4.5\text{V}$	-	-	0.55
input leakage current	I_I	$V_I = 5.5\text{V or GND}; V_{CC}=0\text{V to }5.5\text{V}$	-	± 0.1	± 1	μA
power-off leakage current	I_{OFF}	$V_I \text{ or } V_O = 5.5\text{V}; V_{CC}=0\text{V}$	-	± 0.1	± 2	μA
supply current	I_{CC}	$V_I = 5.5\text{V or GND}; I_O = 0\text{A}; V_{CC}=1.65\text{V to }5.5\text{V}$	-	0.1	4	μA
additional supply current	ΔI_{CC}	per pin; $V_I = V_{CC} - 0.6\text{V}; I_O = 0\text{A}; V_{CC}=2.3\text{V to }5.5\text{V}$	-	5	500	μA
input capacitance	C_I	$V_{CC}=3.3\text{V}; V_I = \text{GND to } V_{CC}$	-	5	-	pF

Note: All typical values are measured at $V_{CC}=3.3\text{V}$ and $T_{amb}=25^{\circ}\text{C}$.

**3.3.2、DC Characteristics 2**(T_{amb}=-40℃ to +105℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V _{IH}	V _{CC} =1.65V to 1.95V		0.65× V _{CC}	-	-	V
		V _{CC} =2.3V to 2.7V		1.7	-	-	V
		V _{CC} =2.7V to 3.6V		2.0	-	-	V
		V _{CC} =4.5V to 5.5V		0.7× V _{CC}	-	-	V
LOW-level input voltage	V _{IL}	V _{CC} =1.65V to 1.95V		-	-	0.35× V _{CC}	V
		V _{CC} =2.3V to 2.7V		-	-	0.7	V
		V _{CC} =2.7V to 3.6V		-	-	0.8	V
		V _{CC} =4.5V to 5.5V		-	-	0.3× V _{CC}	V
HIGH-level output voltage	V _{OH}	V _I = V _{IH} or V _{IL}	I _O =-100uA; V _{CC} =1.65V to 5.5V	V _{CC} - 0.1	-	-	V
			I _O =-4mA; V _{CC} =1.65V	0.95	-	-	V
			I _O =-8mA; V _{CC} =2.3V	1.7	-	-	V
			I _O =-12mA; V _{CC} =2.7V	1.9	-	-	V
			I _O =-24mA; V _{CC} =3.0V	2.0	-	-	V
			I _O =-32mA; V _{CC} =4.5V	3.4	-	-	V
LOW-level output voltage	V _{OL}	V _I = V _{IH} or V _{IL}	I _O =100uA; V _{CC} =1.65V to 5.5V	-	-	0.10	V
			I _O =4mA; V _{CC} =1.65V	-	-	0.70	V
			I _O =8mA; V _{CC} =2.3V	-	-	0.45	V
			I _O =12mA; V _{CC} =2.7V	-	-	0.60	V
			I _O =24mA; V _{CC} =3.0V	-	-	0.80	V
			I _O =32mA; V _{CC} =4.5V	-	-	0.80	V
input leakage current	I _I	V _I =5.5V or GND; V _{CC} =0V to 5.5V		-	-	±1	uA
power-off leakage current	I _{OFF}	V _I or V _O =5.5V; V _{CC} =0V		-	-	±2	uA
supply current	I _{CC}	V _I =5.5V or GND; I _O =0A; V _{CC} =1.65V to 5.5V		-	-	4	uA
additional supply current	ΔI _{CC}	per pin; V _I =V _{CC} -0.6V; I _O =0A; V _{CC} =2.3V to 5.5V		-	-	500	uA

Note: All typical values are measured at V_{CC}=3.3V and T_{amb}=25℃.

**3.3.3、AC Characteristics 1**(T_{amb}=-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
A, B to Y propagation delay	t _{pd}	see Figure 5	V _{CC} =1.65V to 1.95V	1.0	3.1	8.0	ns
			V _{CC} =2.3V to 2.7V	0.5	2.1	5.5	ns
			V _{CC} =2.7V	0.5	2.5	5.5	ns
			V _{CC} =3.0V to 3.6V	0.5	2.1	4.5	ns
			V _{CC} =4.5V to 5.5V	0.5	1.7	4.0	ns
Power dissipation capacitance	C _{PD}	V _{CC} =3.3V; V _I =GND to V _{CC}		-	16	-	pF

Note:

[1] Typical values are measured at T_{amb}=25°C and V_{CC}=1.8V, 2.5V, 2.7V, 3.3V and 5.0V respectively.[2] t_{pd} is the same as t_{PLH} and t_{PHL}.[3] C_{PD} is used to determine the dynamic power dissipation (P_D in uW).

$$P_D = (C_{PD} \times V_{CC}^2 \times f_i \times N) + (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i=input frequency in MHz;f_o=output frequency in MHz;C_L=output load capacitance in pF;V_{CC}=supply voltage in V;

N=number of inputs switching.

3.3.4、AC Characteristics 2(T_{amb}=-40°C to +105°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
A, B to Y propagation delay	t _{pd}	see Figure 5	V _{CC} =1.65V to 1.95V	1.0	-	10.5	ns
			V _{CC} =2.3V to 2.7V	0.5	-	7.0	ns
			V _{CC} =2.7V	0.5	-	7.0	ns
			V _{CC} =3.0V to 3.6V	0.5	-	6.0	ns
			V _{CC} =4.5V to 5.5V	0.5	-	5.5	ns

Note:

[1] Typical values are measured at T_{amb}=25°C and V_{CC}=1.8V, 2.5V, 2.7V, 3.3V and 5.0V respectively.[2] t_{pd} is the same as t_{PLH} and t_{PHL}.



4、Testing Circuit

4.1、AC Testing Circuit

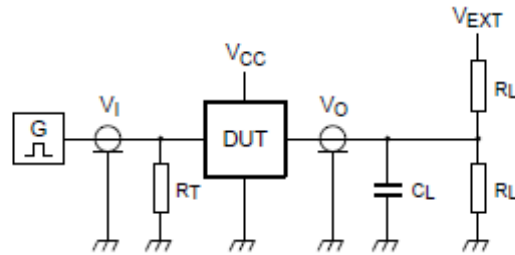


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.

4.2、AC Testing Waveforms

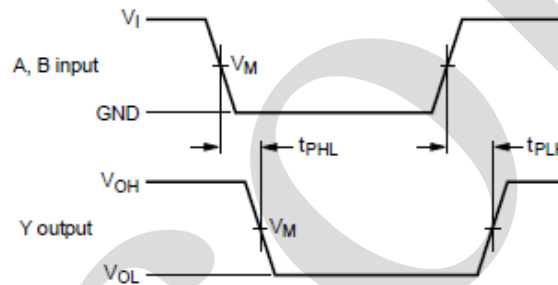


Figure 5. The input A, B to output Y propagation delays

4.3、Measurement Points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

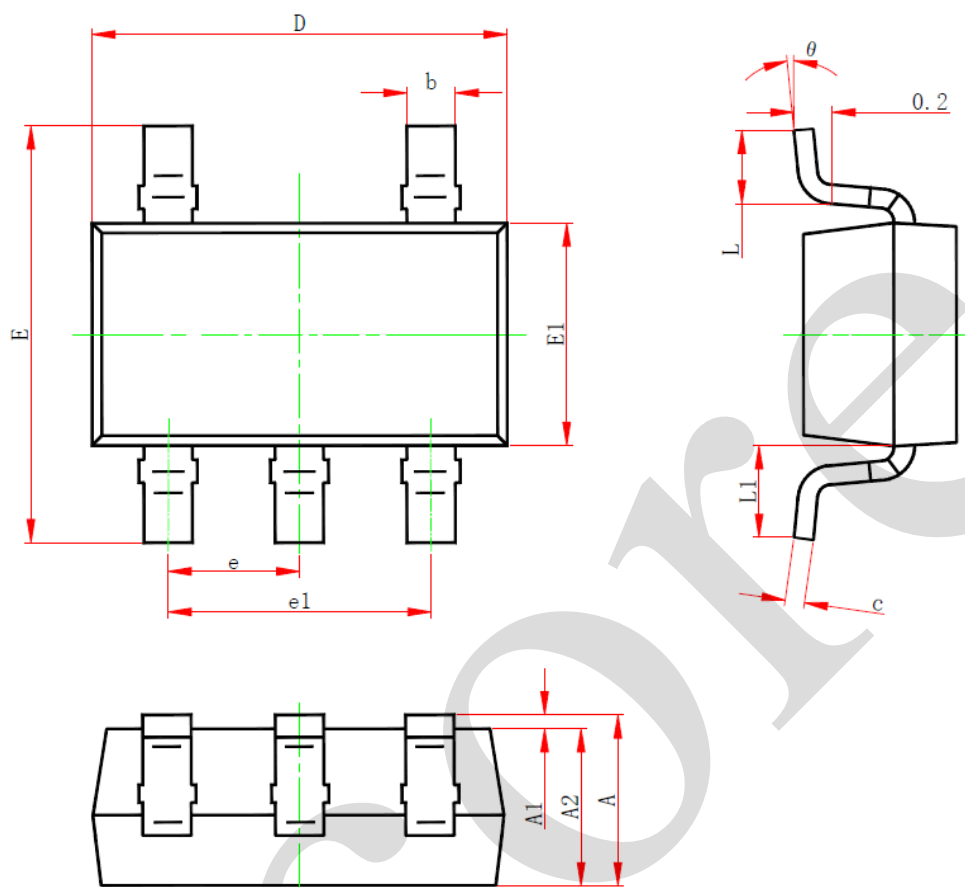
4.4、Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65V to 1.95V	V_{CC}	$\leq 2.0ns$	30pF	1k Ω	open
2.3V to 2.7V	V_{CC}	$\leq 2.0ns$	30pF	500 Ω	open
2.7V	2.7V	$\leq 2.5ns$	50pF	500 Ω	open
3.0V to 3.6V	2.7V	$\leq 2.5ns$	50pF	500 Ω	open
4.5V to 5.5V	V_{CC}	$\leq 2.5ns$	50pF	500 Ω	open



5、Package Information

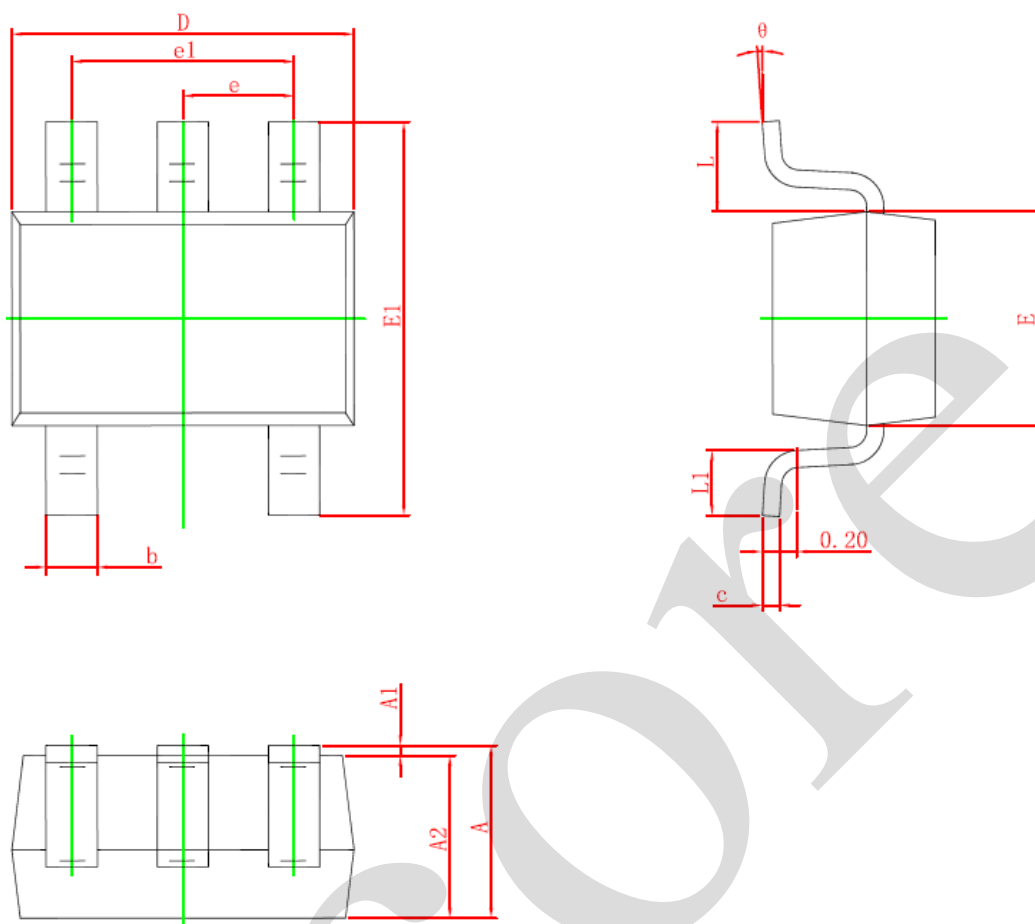
5.1、SOT23-5



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.26
A1	0.00	0.12
A2	1.00	1.20
b	0.30	0.50
c	0.10	0.20
D	2.82	3.02
E	2.60	3.00
E1	1.50	1.70
e	0.95	
e1	1.80	2.00
L	0.30	0.60
θ	0°	8°



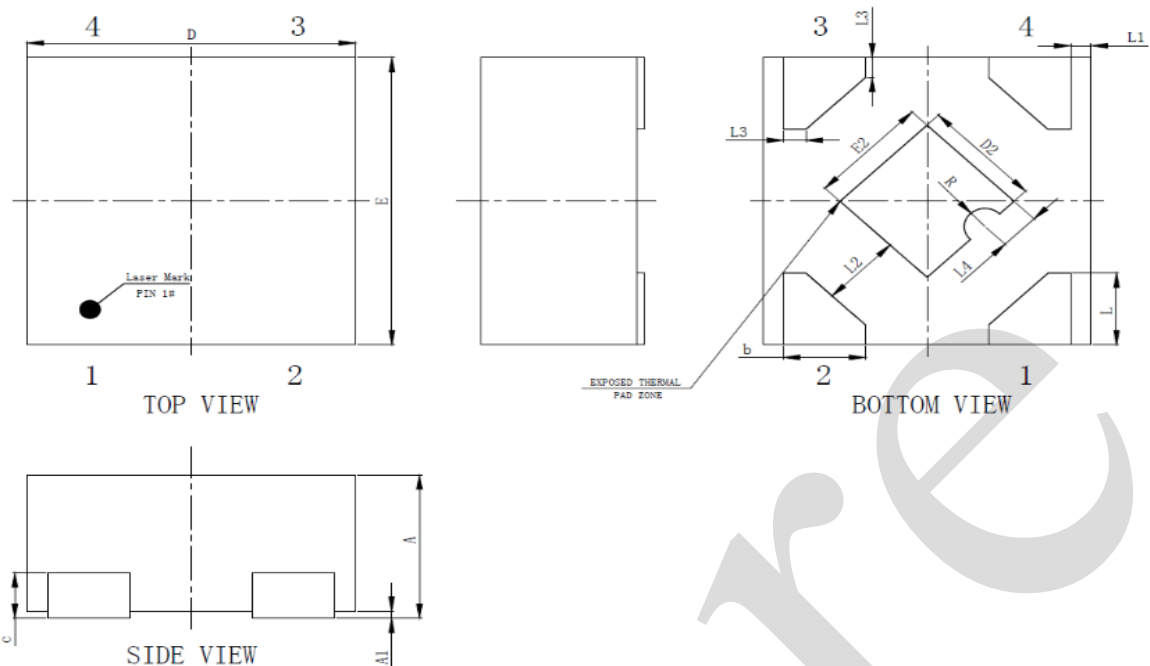
5.2、SOT353



Symbol	Dimensions (mm)	
	Min.	Max.
A	0.90	1.10
A1	0.00	0.10
A2	0.90	1.00
b	0.15	0.35
c	0.11	0.175
D	2.00	2.20
E	1.15	1.35
E1	2.15	2.45
e	0.65	
e1	1.20	1.40
L	0.525	
L1	0.26	0.46
θ	0°	8°



5.3、DFN4



Symbol	Dimensions (mm)	
	Min.	Max.
A	0.37	0.43
A1	0.00	0.05
b	0.15	0.25
c	0.127	
D	0.75	0.85
D2	0.20	0.40
E	0.75	0.85
E2	0.20	0.40
e	0.50	
L	0.15	0.25
L1	0.05	
L2	0.20	
L3	0.055	
L4	0.10	
R	0.05	



6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

6.2、Notes

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